NSN 5961-01-021-0853



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-021-0853

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Inclosure Material:
Metal
Overall Length:
1.573 inches
Overall Height:
0.360 inches
Overall Width:
1.050 inches
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-100.0 collector to base voltage/static/emitter open and -100.0 collector to emitter voltage/static/base open and -5.0 emitter to base
voltage, static, collector open
Current Rating Per Characteristic:
-30.00 amperes source cutoff current and -7.50 amperes source cutoff current
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Precious Material And Location:
Terminal surfaces gold
Precious Material:
Gold
Test Data Document:
82577-928490 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
2 pin and 1 case
Shelf Life:

N/a

Unit Of Measure:

NSN 5961-01-021-0853

Transistor - Page 2 of 2



Demilitarization:

No

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